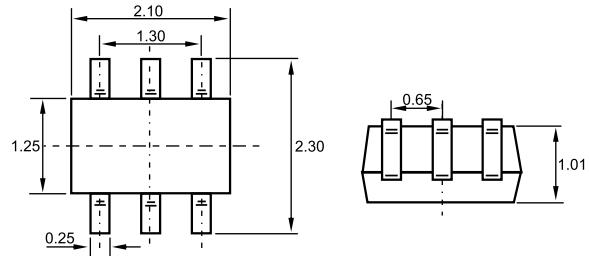


Features

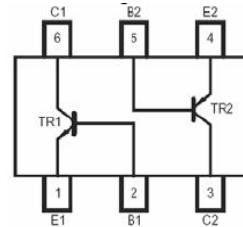
- Epitaxial planar die construction.
- Complementary Pair.
- Ultra-small surface mount package.



SOT-363

Applications

- Ideal for low power amplification and switching .



MAXIMUM RATING ,NPN 2222A Section @ Ta=25°C unless otherwise specified

Symbol	Parameter	Value	Unit
V _{CBO}	Collector-Base Voltage	75	V
V _{CEO}	Collector-Emitter Voltage	40	V
V _{EBO}	Emitter-Base Voltage	6	V
I _C	Collector Current -Continuous	600	mA
P _D	Power Dissipation	200	mW
R _{θJA}	Thermal Resistance, Junction to Ambient	625	°C/W
T _j , T _{stg}	Junction and Storage Temperature	-55 to +150	°C

MAXIMUM RATING ,PNP 2907A Section @ Ta=25°C unless otherwise specified

Symbol	Parameter	Value	Unit
V _{CBO}	Collector-Base Voltage	-60	V
V _{CEO}	Collector-Emitter Voltage	-60	V
V _{EBO}	Emitter-Base Voltage	-5	V
I _C	Collector Current -Continuous	-600	mA
P _D	Power Dissipation	200	mW
R _{θJA}	Thermal Resistance, Junction to Ambient	625	°C/W
T _j , T _{stg}	Junction and Storage Temperature	-55 to +150	°C

ELECTRICAL CHARACTERISTICS OF TR2 , NPN2222A SECTION

@ Ta=25°C unless otherwise specified

Parameter	Symbol	Test conditions	MIN	MAX	UNIT
Collector-base breakdown voltage	$V_{(BR)CBO}$	$I_C=10\mu A, I_E=0$	75	-	V
Collector-emitter breakdown voltage	$V_{(BR)CEO}$	$I_C=10mA, I_B=0$	40	-	V
Emitter-base breakdown voltage	$V_{(BR)EBO}$	$I_E=10\mu A, I_C=0$	6	-	V
Collector cut-off current	I_{CBO}	$V_{CB}=60V, I_E=0$ $V_{CB}=60V, I_E=0, T_A=150^\circ C$	-	10 10	nA μA
Collector cut-off current	I_{CEX}	$V_{CE}=60V, V_{EB(OFF)}=3.0V$	-	10	nA
Emitter cut-off current	I_{EBO}	$V_{EB}=3V I_C=0$	-	10	nA
Base cut-off current	I_{BL}	$V_{CE}=60V V_{EB(OFF)}=3.0V$	-	20	nA
DC current gain	h_{FE}	$V_{CE}=10V, I_C=100\mu A$ $V_{CE}=10V, I_C=1.00mA$ $V_{CE}=10V, I_C=10mA$ $V_{CE}=10V, I_C=150mA$ $V_{CE}=10V, I_C=500mA$ $V_{CE}=10V, I_C=10mA, T_A=-55^\circ C$ $V_{CE}=1.0V, I_C=150mA,$	35 50 75 100 40 50 35	- - - 300 - - -	
Collector-emitter saturation voltage	$V_{CE(sat)}$	$I_C=150mA I_B=15mA$ $I_C=500mA I_B=50mA$	-	0.3 1.0	V
Base-emitter saturation voltage	$V_{BE(sat)}$	$I_C=150mA I_B=15mA$ $I_C=500mA I_B=50mA$	0.6 -	1.2 2.0	V
Transition frequency	f_T	$V_{CE}=20V, I_C=20mA, f=100MHz$	300	-	MHz
Output Capacitance	C_{obo}	$V_{CB}=10V, f=1.0MHz, I_E=0$	-	8	pF
Input Capacitance	C_{ibo}	$V_{EB}=0.5V, f=1.0MHz, I_C=0$	-	25	pF
Noise Figure	NF	$V_{CE}=10V, f=1.0kHz, I_C=0.1mA$ $R_g=1.0K\Omega,$	-	4.0	dB
Delay Time	t_d	$V_{CC}=30V, I_C=150mA,$	-	10	ns
Rise Time	t_r	$V_{BE(off)}=-0.5V, I_{B1}=15mA$	-	25	ns

ELECTRICAL CHARACTERISTICS OF TR2, PNP2907A SECTION

@ Ta=25°C unless otherwise specified

Parameter	Symbol	Test conditions	MIN	MAX	UNIT
Collector-base breakdown voltage	$V_{(BR)CBO}$	$I_C=-10\mu A I_E=0$	-60	-	V
Collector-emitter breakdown voltage	$V_{(BR)CEO}$	$I_C=-10mA I_B=0$	-60	-	V
Emitter-base breakdown voltage	$V_{(BR)EBO}$	$I_E=-10\mu A I_C=0$	-5	-	V
Collector cut-off current	I_{CBO}	$V_{CB}=-50V I_E=0$ $V_{CB}=-50V I_E=0 T_A=125^\circ C$	-	-10	nA μA
Collector cut-off current	I_{CEX}	$V_{CE}=-30V V_{EB(OFF)}=-0.5V$	-	-50	nA
Base cut-off current	I_{BL}	$V_{CE}=-30V V_{EB(OFF)}=-0.5V$	-	-50	nA
DC current gain	h_{FE}	$V_{CE}=-10V I_C=-100\mu A$ $V_{CE}=-10V I_C=-1mA$ $V_{CE}=-10V I_C=-10mA$ $V_{CE}=-10V I_C=-150mA$ $V_{CE}=-10V I_C=-500mA$	75 100 100 100 50	- - - 300 -	
Collector-emitter saturation voltage	$V_{CE(sat)}$	$I_C=-150mA I_B=-15mA$ $I_C=-500mA I_B=-50mA$	-	-0.4 -1.6	V
Base-emitter saturation voltage	$V_{BE(sat)}$	$I_C=-150mA I_B=-15mA$ $I_C=-500mA I_B=-50mA$	-	-1.3 -2.6	V
Transition frequency	f_T	$V_{CE}=-20V, I_C=-50mA, f=100MHz$	200	-	MHz
Output Capacitance	C_{obo}	$V_{CB}=-10V, f=1.0MHz, I_E=0$	-	-8.0	pF
Input Capacitance	C_{ibo}	$V_{EB}=-2.0V, f=1.0MHz, I_C=0$	-	30	pF
Turn-on time	t_{on}	$I_C=-150mA, V_{CC}=-30V, I_{B1}=-15mA$	-	45	ns
Delay Time	t_d	$V_{CC}=-30V, I_C=-150mA, I_{B1}=-15mA$	-	10	ns
Rise Time	t_r		-	40	ns

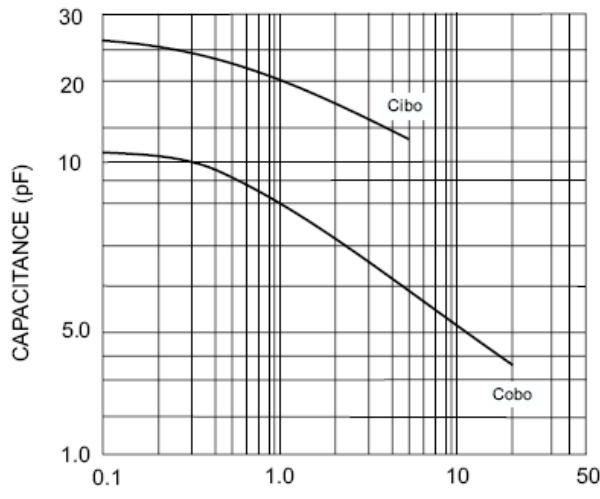
TYPICAL CHARACTERISTICS @ $T_a=25^\circ C$ unless otherwise specified


Fig. 1 (2222A) Capacitances (Typical)

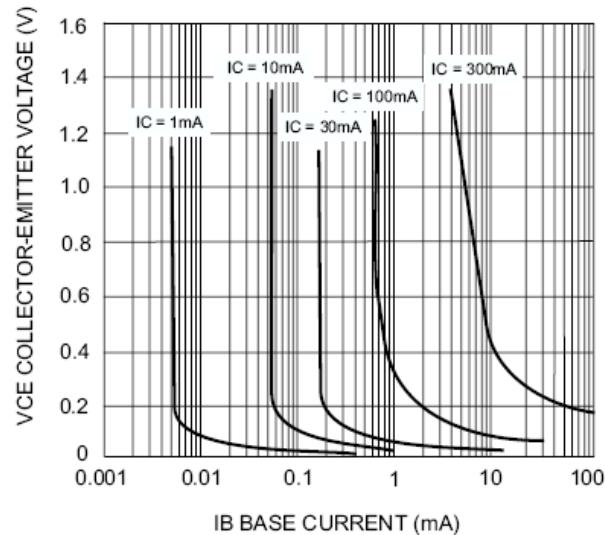


Fig. 4 (2907A) Typical Collector Saturation Region

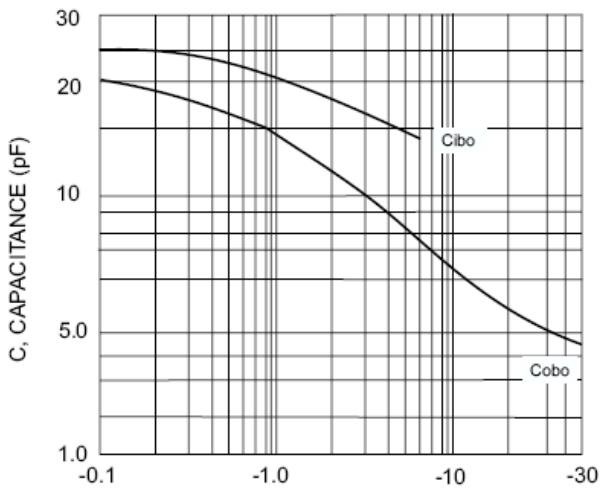


Fig. 3 (2907A) Capacitances (Typical)

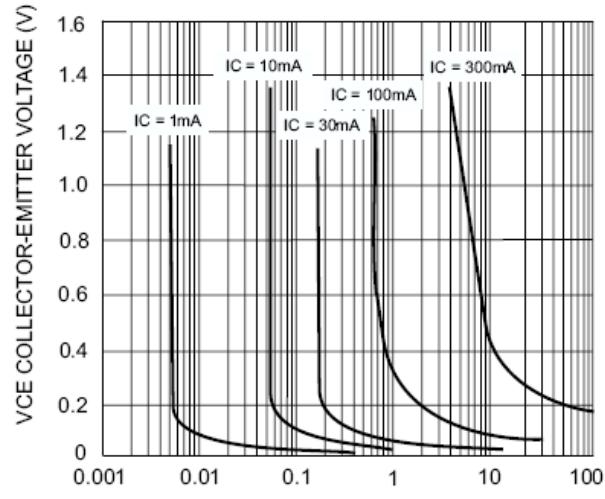


Fig. 4 (2907A) Typical Collector Saturation Region

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